## NSN 5961-00-298-2168

Thyristor Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-298-2168
Inclosure Material:
Metal
Overall Length:
Between 0.250 inches and 0.260 inches
Terminal Length:
0.360 inches
Overall Diameter:
0.420 inches
Internal Configuration:
Junction contact
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited
Current Rating Per Characteristic:
2.00 amperes zero-gate-voltage source current horsepower metric
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 tab, solder lug and 1 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
<del></del>
Demilitarization:
No
Fiig:
A110a0